



# Bipolar PNP Bare Die – BTP199

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## Part Description

The BTP199 is a silicon BJT transistor available in bare die form and well suited for use in High Speed Switching applications.

## Key Parameters:

- VCBO = -60V
- VCEO = -60V
- VEBO = -5V
- hFE = 90-333 @ VCE = -10V, IC = -0.15A
- VCE(Sat) = -1.6V @ IC = -0.5A, IB = -50mA
- fT = 200 MHz @ VCE = -20V, IE = 0A
- COBO = 10pF @ VCB = -10V

## Features

Designed to provide performance equivalent to FAIRCHILD / ON SEMI MMBT2907A, 2N2907A

## Die Size (Unseen)

490µm X 490µm, 19 Mils X 19 Mils

This is a shortform datasheet only

For the full datasheet

Please contact [sales@siliconsupplies.com](mailto:sales@siliconsupplies.com)

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